TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74LVX32F, TC74LVX32FN, TC74LVX32FT

QUAD 2-INPUT OR GATE

The TC74LVX32 is a high speed CMOS 2-INPUT OR GATE fabricated with silicon gate C²MOS technology.

Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low voltage and battery operated systems.

The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output.

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

• High speed : $t_{pd} = 4.4$ ns (Typ.)

 $(V_{CC} = 3.3V)$

• Low power dissipation : $I_{CC} = 2\mu A$ (Max.) (Ta = 25°C)

• Input voltage level : $V_{IL} = 0.8V$ (Max.) ($V_{CC} = 3V$)

 $V_{IH} = 2.0V \text{ (Min.) } (V_{CC} = 3V)$

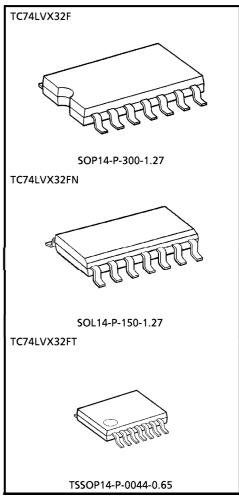
• Power down protection is provided on all inputs.

Balanced propagation delays : tplH≃tpHL

• Low noise : $V_{OLP} = 0.5V$ (Max.)

Pin and function compatible with 74HC32

(Note) The JEDEC SOP (FN) is not available in Japan.



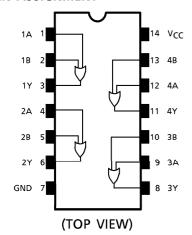
Weight

SOP14-P-300-1.27 : 0.18g (Typ.) SOL14-P-150-1.27 : 0.12g (Typ.) TSSOP14-P-0044-0.65 : 0.06g (Typ.)

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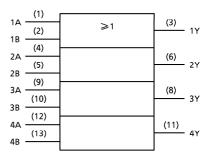
PIN ASSIGNMENT



TRUTH TABLE

INPUTS		OUTPUTS
Α	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

IEC LOGIC SYMBOL



MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage Range	Vcc	-0.5~7.0	V
DC Input Voltage	VIN	-0.5~7.0	٧
DC Output Voltage	VOUT	-0.5~V _{CC} +0.5	V
Input Diode Current	Ικ	- 20	mA
Output Diode Current	Ioк	± 20	mA
DC Output Current	IOUT	± 25	mA
DC V _{CC} / Ground Current	ICC	± 50	mA
Power Dissipation	PD	180	mW
Storage Temperature	T _{stg}	-65∼150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	2.0~3.6	٧
Input Voltage	VIN	0~5.5	٧
Output Voltage	Vout	0~V _{CC}	V
Operating Temperature	T _{opr}	- 40~85	°C
Input Rise And Fall Time	dt/dv	0~100	ns / V

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ELECTRICAL CHARACTERISTICS

DC characteristics

PARAMETER		SYM- TEST CONDITION		Vcc	7	Γa = 25°0	<u> </u>	Ta = -4	∙0~85°C	UNIT	
FARA	IVIETER	BOL	1231 CONDITION		(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UIVII
			2.0	1.5	_	_	1.5	_			
"H" Leve	"H" Level	V_{IH}			3.0	2.0	_	_	2.0	_	
Input					3.6	2.4	_	_	2.4	_	l _v l
Voltage					2.0	_	_	0.5	_	0.5	
	"L" Level	V_{IL}			3.0	_	_	0.8	_	0.8	
					3.6	_	_	0.8	_	0.8	
		V _{OH}	V _{IN} = V _{IH}	$I_{OH} = -50\mu A$	2.0	1.9	2.0	_	1.9	_	
	"H" Level			$I_{OH} = -50\mu A$	3.0	2.9	3.0	_	2.9	_	
Output			or V_{IL}	$I_{OH} = -4mA$	3.0	2.58	_	_	2.48	_	v
Voltage				$I_{OL} = 50 \mu A$	2.0	_	0.0	0.1	_	0.1	
	"L" Level	VOL	$V_{IN} = V_{IL}$	$I_{OL} = 50 \mu A$	3.0	_	0.0	0.1	_	0.1	
				I _{OL} = 4mA	3.0	_	_	0.36	_	0.44	
Input Leakage Current I_{IN} $V_{IN} = 5.5V$ or GND		3.6	_	_	±0.1	_	± 1.0	μ A			
Quiescent S Current	Supply	lcc	V _{IN} = V _{CC} o	or GND	3.6	_	_	2.0	_	20.0	μΑ

AC characteristics (Input $t_r = t_f = 3ns$)

PARAMETER	SYM-					Ta = 25°C			$Ta = -40 \sim 85^{\circ}C$						
PARAIVIETER	BOL	CONDITION	V _{CC} (V)	C _L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT					
	4		2.7	15	_	5.8	10.7	1.0	13.5						
Propagation Delay	t _{pLH}		2.7	50	_	8.3	14.2	1.0	17.0	ns					
Time	₊		22+02	15	_	4.4	6.6	1.0	8.0	1113					
	t _{pHL}		3.3 ± 0.3	50	_	6.9	10.1	1.0	11.5						
Output To Output	tosLH	(Note 1)	2.7	50	_	_	1.5	_	1.5	ne					
Skew	tosHL	(Note 1)	(Note 1)	(Note 1)	(NOCE I)	(Note 1)	HL (Note 1)	3.3 ± 0.3	50	_	_	1.5	_	1.5	ns
Input Capacitance	CIN	(Note 2)			_	4	10	_	10	pF					
Power Dissipation Capacitance	C _{PD}	(Note 3)			_	14	_	_	_	pF					

(Note 1) Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

(Note 2) Parameter guaranteed by design.

(Note 3) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

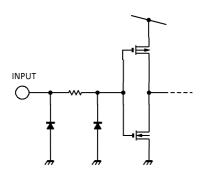
Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per Gate)}$

Noise characteristics (Ta = 25°C, Input $t_r = t_f = 3$ ns, $C_L = 50$ pF)

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PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}		3.3	0.3	0.5	٧
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}		3.3	-0.3	-0.5	V
Minimum High Level Dynamic Input Voltage	V _{IHD}		3.3	_	2.0	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}		3.3	_	0.8	V

INPUT EQUIVALENT CIRCUIT



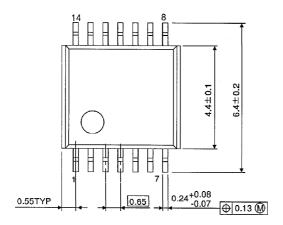
OUTLINE DRAWING SOP14-P-300-1.27 Unit:mm 1.34TYP 1.0.8MAX 10.3±0.2 10.8MAX 10.3±0.2 10.8+0.2

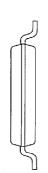
OUTLINE DRAWING SOL14-P-150-1.27 Unit: mm (Note) This package is not available in Japan. 14 8 3.9 ± 0.1 6.0±0.2 H 7 0.515TYP 0.42±0.07 **⊕** 0.25 **⋈** 1.27 8.65±0.1 45° 0.175±0.075 **2**0.1 7် ဝ 0.7±0.3

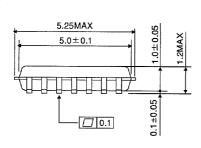
Weight: 0.12g (Typ.)

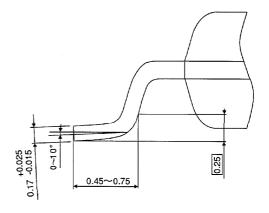
Unit: mm

OUTLINE DRAWING TSSOP14-P-0044-0.65









Weight: 0.06g (Typ.)

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